

TRI-STATE BUFFER
■ GENERAL DESCRIPTION

The NJU6342 is a tri-state buffer input the external ECL oscillation signal and output C-MOS level signal.

It consists of an amplifier and tri-state output buffer.

The input/output frequency is as wide as up to 120MHz and the symmetry of 45-55% is realized over full operating frequency range.

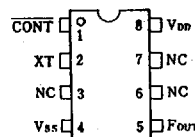
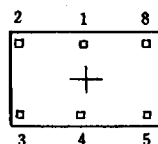
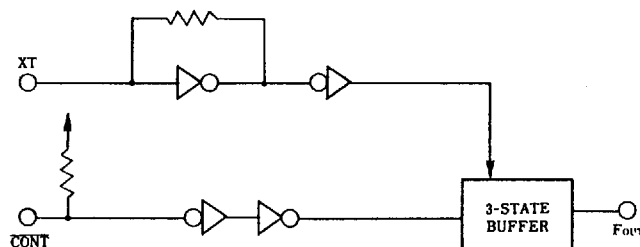
The output buffer is TTL compatible and capable of 5 TTL driving.

■ PACKAGE OUTLINE

NJU6342C

NJU6342E
■ FEATURES

- Operating Voltage — 4.0~6.0V
- Maximum Oscillation Frequency — 120MHz
- Low Operating Current
- High Fan-out — TTL 5
- Selected Frequency Output (mask option)
Only one frequency out of f_o , $f_o/2$, $f_o/4$ and $f_o/8$ output
- Oscillation and/or Output Stand-by Function
- Package Outline — CHIP/EMP 8
- C-MOS Technology

■ PIN CONFIGURATION/PAD LOCATION

■ BLOCK DIAGRAM

■ COORDINATES

 Unit: μm

No.	PAD	X	Y
1	CONT	- 29	181
2	XT	- 462	181
3	NC	- 463	- 181
4	V _{SS}	- 44	- 229
5	F _{OUT}	564	- 229
8	V _{DD}	564	229

Chip Size : 1.49 X 0.8mm
Chip Thickness : 400 μm X 30 μm

■ TERMINAL DESCRIPTION

NO.	SYMBOL	F U N C T I O N
1	CONT	Tri-state output control terminal
		CONT F _{OUT}
		H Input ECL oscillation signal output
		L Output High Impedance
2	XT	External ECL oscillation signal input terminal
4	V _{SS}	GND
5	F _{OUT}	Output amplified external ECL oscillation frequency
8	V _{DD}	+ 5V

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■ ABSOLUTE MAXIMUM RATINGS

(Ta=25℃)

P A R A M E T E R	S Y M B O L	R A T I N G S	U N I T
Supply Voltage	V _{DD}	- 0.3 ~ +7.0	V
Input Voltage	V _{IN}	V _{SS} -0.3 ~ V _{DD} +0.3	V
Output Voltage	V _O	- 0.5 ~ V _{DD} +0.5	V
Input Current	I _{IN}	±10	mA
Output Current	I _O	±25	mA
Power Dissipation (EMP)	P _D	200	mW
Operating Temperature Range	T _{opr}	- 30 ~ + 75	℃
Storage Temperature Range	T _{stg}	- 40 ~ +125	℃

■ ELECTRICAL CHARACTERISTICS

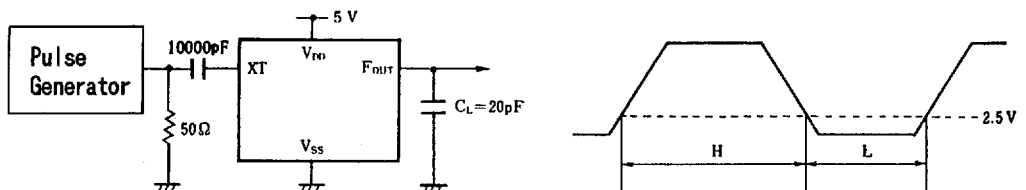
 ($T_a=25^{\circ}\text{C}$, $V_{DD}=5\text{V}$)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Voltage	V_{DD}		4	5	6	V
Operating Current	I_{DD}	$f_{IN}=120\text{MHz}$, $V_{IN}=0.5\text{V}_{P-P}$ No load			65	mA
Stand-by Current	I_{st}	$\overline{\text{CONT}}=\text{XT}=\overline{V_{SS}}$, No load (Note)			1	μA
Input Voltage	V_{IH}	$\overline{\text{CONT}}$ Terminal	4.5		5.0	V
	V_{IL}		0		0.5	
Output Current	I_{OH}	$V_{OH}=4.5\text{V}$	24			mA
	I_{OL}	$V_{OL}=0.5\text{V}$	24			
Output Voltage	V_{OH}	$I_{OH}=-24\text{mA}$	4.5		5.0	V
	V_{OL}	$I_{OL}=+24\text{mA}$	0		0.5	
Input Current	I_{IN}	$\overline{\text{CONT}}$ Terminal, $\overline{\text{CONT}}=\overline{V_{SS}}$	125	250	500	μA
Tri-state Off-leakage Current	I_{OZ}	$\overline{\text{CONT}}=\overline{V_{SS}}$, $F_{OUT}=\overline{V_{DD}}$ or $\overline{V_{SS}}$			± 1	μA
Max. Operating Frequency	f_{MAX}				120	MHz
Output Signal Symmetry	SYM	$C_L=20\text{pF}$, at 2.5V , $f_{IN}=120\text{MHz}$ $V_{IN}=0.5\text{V}_{P-P}$	45	50	55	%
Output Signal Rise Time	t_r	$C_L=20\text{pF}$, $R_L=450\Omega$, 20% - 80%		0.8		ns
Output Signal Fall Time	t_f	$C_L=20\text{pF}$, $R_L=450\Omega$, 80% - 20%		0.8		

 Note) Excluding input current on $\overline{\text{CONT}}$ terminal.

■ MEASUREMENT CIRCUITS

(1) Output Symmetry



(2) Output Rise / Fall Time

